CLAIMS:

What is claimed is:

- 1 1. A reduced sensitivity spin valve sensor apparatus,
- 2 comprising:
- at least one fixed layer; and
- 4 at least one free layer, wherein the flux carrying
- 5 capacity of the spin valve sensor is increased above
- 6 standard spin valve sensors, to reduce the sensitivity of
- 7 the spin valve sensor.
- 1 2. The reduced sensitivity spin valve sensor apparatus
- of claim 1, wherein the flux carrying capacity of the
- 3 spin valve sensor is increased by increasing a thickness
- 4 of the at least one free layer above 60 angstroms.
- 1 3. The reduced sensitivity spin valve sensor apparatus
- of claim 2, wherein the thickness of the at least one
- 3 free layer is between 90 and 120 angstroms, inclusively.
- 1 4. The reduced sensitivity spin valve sensor apparatus
- of claim 1, wherein the flux carrying capacity of the
- 3 spin valve sensor is increased above standard spin valve
- 4 sensors such that an amount by which a free layer moment
- 5 rotates for a given flux input is decreased.
- 1 5. A reduced sensitivity spin valve sensor apparatus,
- 2 comprising:
- 3 at least one fixed layer; and
- 4 at least two free layers.

- 1 6. The reduced sensitivity spin valve sensor apparatus
- of claim 5, further comprising at least one non-magnetic
- 3 spacer positioned between the at least one fixed layer
- 4 and one of the at least two free layers.
- 1 7. The reduced sensitivity spin valve sensor apparatus
- 2 of claim 5, wherein the at least one fixed layer includes
- 3 at least two fixed layers having a magnetic orientation
- 4 approximately 90 degrees from a magnetic orientation of
- 5 the at least two free layers.
- 1 8. The reduced sensitivity spin valve sensor apparatus
- 2 of claim 5, wherein the at least one fixed layer includes
- 3 at least two fixed layers, and wherein the at least two
- 4 free layers are positioned between the at least two fixed
- 5 layers.
- 1 9. The reduced sensitivity spin valve sensor apparatus
- of claim 8, wherein the at least two fixed layers and the
- 3 at least two free layers are spaced from one another by
- 4 three non-magnetic spacers.
- 1 10. The reduced sensitivity spin valve sensor apparatus
- 2 of claim 5, wherein a magnetic flux is distributed across
- 3 the two free layers to thereby reduce a magnetic flux fed
- 4 to each free layer.

- 1 11. A method of making a reduced sensitivity spin valve
- 2 sensor apparatus, comprising:
- 3 providing at least one fixed layer; and
- 4 providing at least one free layer, wherein the flux
- 5 carrying capacity of the spin valve sensor is increased
- 6 above standard spin valve sensors, to reduce the
- 7 sensitivity of the spin valve sensor.
- 1 12. The method of making a reduced sensitivity spin
- 2 valve sensor apparatus of claim 1, wherein the flux
- 3 carrying capacity of the spin valve sensor is increased
- 4 by increasing a thickness of the at least one free layer
- 5 above 60 angstroms.
- 1 13. The method of making a reduced sensitivity spin
- 2 valve sensor apparatus of claim 12, wherein the thickness
- 3 of the at least one free layer is between 90 and 120
- 4 angstroms, inclusively.
- 1 14. The method of making a reduced sensitivity spin
- 2 valve sensor apparatus of claim 11, wherein the flux
- 3 carrying capacity of the spin valve sensor is increased
- 4 above standard spin valve sensors such that an amount by
- 5 which a free layer moment rotates for a given flux input
- 6 is decreased.
- 1 15. A method of making a reduced sensitivity spin valve
- 2 sensor apparatus, comprising:
- 3 providing at least one fixed layer; and
- 4 providing at least two free layers.

- 1 16. The method of making a reduced sensitivity spin
- 2 valve sensor apparatus of claim 15, further comprising
- 3 providing at least one non-magnetic spacer positioned
- 4 between the at least one fixed layer and one of the at
- 5 least two free layers.
- 1 17. The method of making a reduced sensitivity spin
- 2 valve sensor apparatus of claim 15, wherein providing the
- 3 at least one fixed layer includes providing at least two
- 4 fixed layers having a magnetic orientation approximately
- 5 90 degrees from a magnetic orientation of the at least
- 6 two free layers.
- 1 18. The method of making a reduced sensitivity spin
- 2 valve sensor apparatus of claim 15, wherein providing the
- 3 at least one fixed layer includes providing at least two
- 4 fixed layers, and wherein providing the at least two free
- 5 layers includes positioning the at least two free layers
- 6 between the at least two fixed layers.
- 1 19. The method of making a reduced sensitivity spin
- 2 valve sensor apparatus of claim 18, wherein providing the
- 3 at least two fixed layers and providing the at least two
- 4 free layers includes spacing the at least two fixed
- 5 layers and at least two free layers from one another by
- 6 three non-magnetic spacers.

- 1 20. The method of making a reduced sensitivity spin
- 2 valve sensor apparatus of claim 15, wherein a magnetic
- 3 flux is distributed across the two free layers to thereby
- 4 reduce a magnetic flux fed to each free layer.